



40V +175°C DUAL N-CHANNEL ENHANCEMENT MODE MOSFET

Product Summary

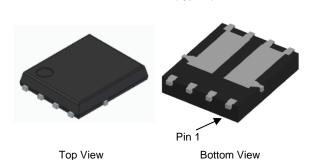
BV _{DSS}	R _{DS(ON)} Max	I _D Max T _C = +25°C (Note 4)	
40V	8.6mΩ @ V _{GS} = 10V	45A	

Description and Applications

This MOSFET is designed to minimize the on-state resistance (R_{DS(ON)}) yet maintain superior switching performance, marking it ideal for high-efficiency power-management applications.

- Backlighting
- Power-management functions
- DC-DC converters

Site 1:



PowerDI5060-8 (Type C)

Features and Benefits

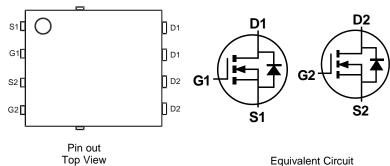
- Rated to +175°C Ideal for High Ambient Temperature **Environments**
- High Conversion Efficiency
- Low R_{DS(ON)} Minimizes On-State Losses
- Low Input Capacitance
- Fast Switching Speed
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- This part is qualified to JEDEC standards (as references in AEC-Q) for High Reliability.

https://www.diodes.com/quality/product-definitions/

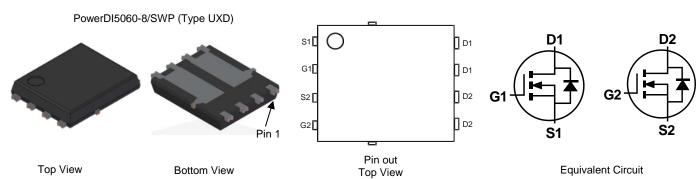
An automotive-compliant part is available under separate datasheet (DMTH4007SPDQ)

Mechanical Data

- Package: PowerDI®5060-8
- Package Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 @3
- Weight: 0.097 grams (Approximate)



Site 2:



1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. Notes:

- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + CI) and <1000ppm antimony compounds.
- 4. Package limited.



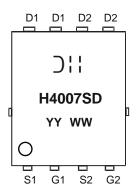
Ordering Information (Note 5)

Part Number	Package	Packing		
Fait Nullibei	Fackage	Qty.	Carrier	
DMTH4007SPD-13	PowerDI5060-8 (Type C)	2,500	Tape & Reel	
DIVITH40073FD-13	PowerDI5060-8/SWP (Type UXD)	2,500	Tape & Reel	

Note:

5. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information



⊃¦¦ = Manufacturer's Marking H4007SD = Product Type Marking Code YYWW or YYWW = Date Code Marking YY or \overline{YY} = Year (ex: 23 = 2023) WW = Week (01 to 53)

Maximum Ratings (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
Drain-Source Voltage			VDSS	40	V
Gate-Source Voltage			Vgss	±20	V
Continuous Drain Current (Note 6)		Tc = +25°C (Note 4) Tc = +100°C	Ι _D	45 38.1	А
ICONTINUOUS Drain Current (Note 7)		T _A = +25°C T _A = +100°C	lo	14.2 11.9	А
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)			I _{DM}	90	Α
Maximum Continuous Body Diode Forward Current (Note 6)			ls	34	Α
Avalanche Current, L = 0.1mH			las	20	Α
Avalanche Energy, L = 0.1mH			Eas	89	mJ

Thermal Characteristics

Characteristic		Symbol	Value	Unit
Total Power Dissipation (Note 7)	T _A = +25°C	PD	2.6	W
Thermal Resistance, Junction to Ambient (Note 7)	Steady State	Reja	57	°C/W
Total Power Dissipation (Note 6)	T _C = +25°C	P _D	37.5	W
Thermal Resistance, Junction to Case (Note 6)	Rejc	4	°C/W	
Operating and Storage Temperature Range		TJ, TSTG	-55 to +175	°C

Notes:

6. Thermal resistance from junction to soldering point (on the exposed drain pad).7. Device mounted on FR-4 substrate PC board, 2oz. copper, with thermal bias to bottom layer 1inch square copper plate.



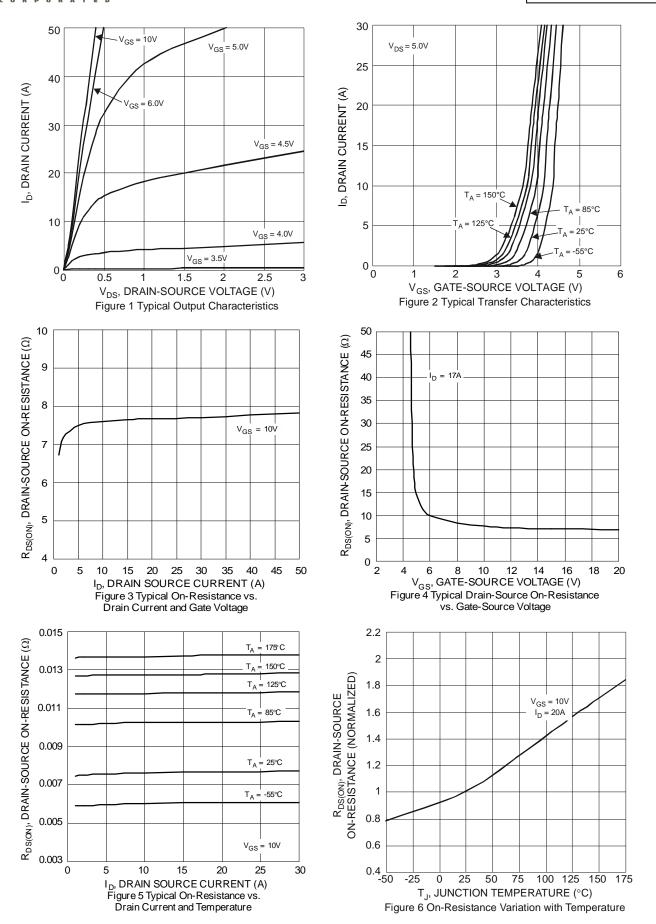
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 8)							
Drain-Source Breakdown Voltage	BV _{DSS}	40	_	_	V	VGS = 0V, ID = 1mA	
Zero Gate Voltage Drain Current	IDSS		_	1	μΑ	V _{DS} = 32V, V _{GS} = 0V	
Gate-Source Leakage	Igss		_	±100	nA	$V_{GS} = \pm 20V$, $V_{DS} = 0V$	
ON CHARACTERISTICS (Note 8)							
Gate Threshold Voltage	Vgs(TH)	2		4	V	$V_{DS} = V_{GS}$, $I_D = 250\mu A$	
Static Drain-Source On-Resistance	R _{DS(ON)}		7.5	8.6	mΩ	$V_{GS} = 10V, I_D = 17A$	
Diode Forward Voltage	V_{SD}		0.85	_	V	$V_{GS} = 0V$, $I_S = 17A$	
DYNAMIC CHARACTERISTICS (Note 9)							
Input Capacitance	Ciss		2,026	_	pF	V _{DS} = 30V, V _{GS} = 0V f = 1MHz	
Output Capacitance	Coss		702	_	pF		
Reverse Transfer Capacitance	Crss		84.8	_	pF		
Gate Resistance	Rg		0.46	_	Ω	$V_{DS} = 0V$, $V_{GS} = 0V$, $f = 1MHz$	
Total Gate Charge	Qg		41.9	_	nC		
Gate-Source Charge	Q_{gs}		10	_	nC	$V_{DS} = 30V, I_D = 20A, V_{GS} = 10V$	
Gate-Drain Charge	Q_{gd}		11.5	_	nC	1	
Turn-On Delay Time	tD(ON)		7	_	ns		
Turn-On Rise Time	t _R		11.5	_	ns	$V_{DD} = 30V, V_{GS} = 10V$ $I_{D} = 20A, R_{G} = 3\Omega$	
Turn-Off Delay Time	tD(OFF)		15.6	_	ns		
Turn-Off Fall Time	tF		8.8	_	ns		
Body Diode Reverse Recovery Time	trr		29.9	_	ns	1_ = 20A d1/dt = 400A/	
Body Diode Reverse Recovery Charge	Q _{RR}		23	_	nC	I _F = 20A, dI/dt = 100A/µs	

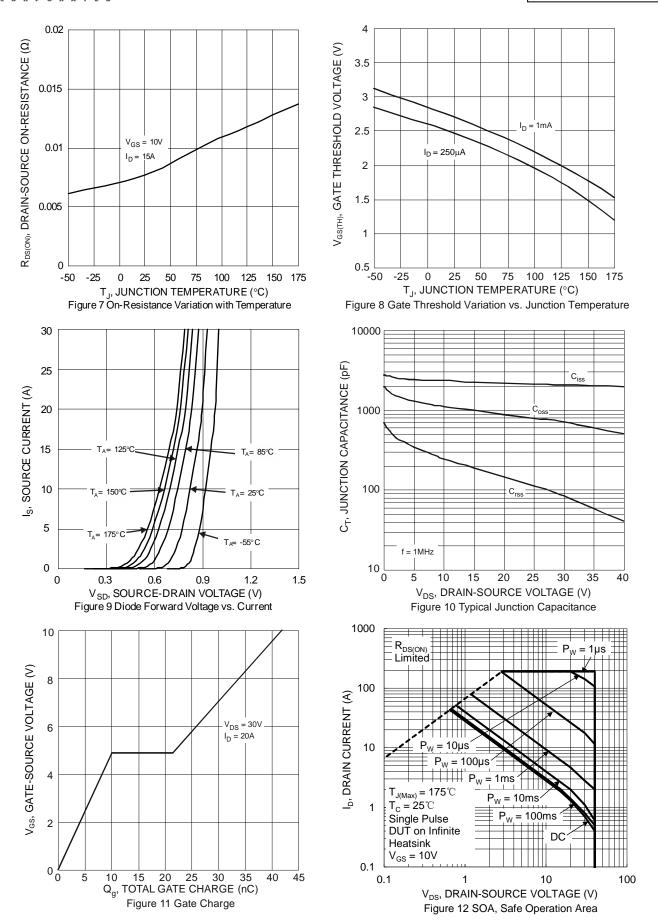
Notes:

^{8.} Short duration pulse test used to minimize self-heating effect. 9. Guaranteed by design. Not subject to product testing.

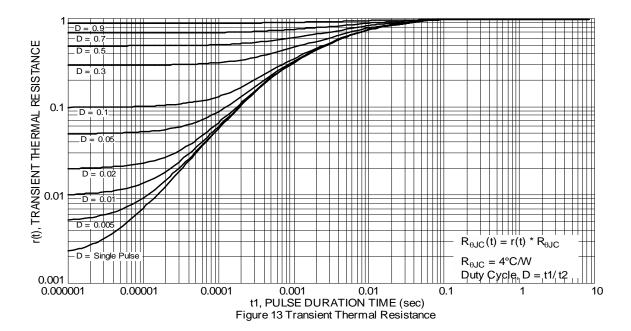












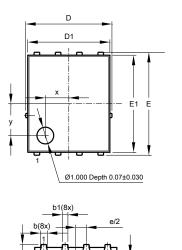


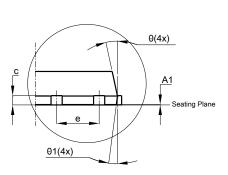
Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

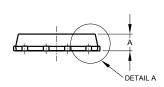
Site 1:

PowerDI5060-8 (Type C)





b1(8x) b(8x) e/2 b2(2x) b2(2x) b2(2x)

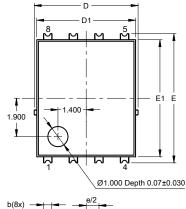


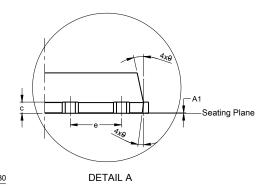
DETAIL A

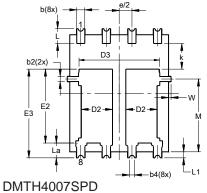
PowerDI5060-8 (Type C) Dim Min Max Тур 0.90 1.10 1.00 Α1 0.05 0.02 0 b 0.33 0.51 0.41 b1 0.300 0.366 0.333 b2 0.20 0.35 0.25 0.23 0.33 0.277 С D 5.15 BSC D1 4.95 4.85 4.90 D2 1.40 1.50 1.60 D3 3.98 Ε 6.15 BSC E1 5.85 5.75 5.80 E2 3.56 3.76 3.66 е 1.27BSC 1.27 k1 0.56 0.51 0.71 0.61 0.61 La 0.51 0.71 L1 0.05 0.20 0.175 L4 0.125 М 3.50 3.71 3.605 1.400 1.900 θ 10° 12° 11° θ1 6° 8° 7° All Dimensions in mm

Site 2:

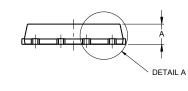
PowerDI5060-8/SWP (Type UXD)







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PowerDI5060-8/SWP					
(Type UXD)					
Dim	Min	Max	Тур		
Α	0.90	1.10	1.00		
A1	0.00	0.05			
b	0.30	0.50	0.41		
b2	0.20	0.35	0.25		
b4	().25REF	-		
С	0.230	0.330	0.277		
D	5	.15 BS0			
D1	4.70	5.10	4.90		
D2	1.46	1.66	1.55		
D3	3.78	4.18	3.98		
Е	6	.40 BS0	\sim		
E1	5.60	6.00	5.80		
E2	3.46	3.86	3.66		
E2a	4.195	4.595	4.395		
е	1	.27BSC)		
k	1.05				
L	0.635	0.835	0.735		
La	0.635	0.835	0.735		
L1	0.200	0.400	0.300		
M	3.205	4.005	3.605		
W	0.025	0.225	0.125		
θ	10°	12°	11°		
θ1	6°	8°	7°		
All Dimensions in mm					

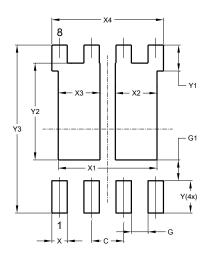


Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

Site 1:

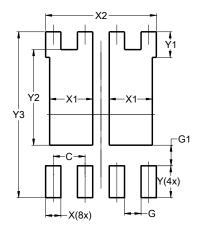
PowerDI5060-8 (Type C)



Dimensions	Value
Dilliensions	(in mm)
С	1.270
G	0.660
G1	0.820
X	0.610
X1	3.910
X2	1.650
Х3	1.650
X4	4.420
Y	1.270
Y1	1.020
Y2	3.810
Y3	6.610

Site 2:

PowerDI5060-8/SWP (Type UXD)



Dimensions	Value
Dilliensions	(in mm)
С	1.270
G	0.660
G1	0.820
Х	0.610
X1	1.720
X2	4.420
Υ	1.270
Y1	1.020
Y2	3.810
Y3	6.610



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